

PRELIMINARY DATA SHEET

NEC

Solid State Relay
OCMOS FET

PS7241H-1A

**4-PIN SOP HIGH ISOLATION VOTAGE 3 750 Vr.m.s.
(1-ch Optical Coupled MOS FET)**

DESCRIPTION

The PS7241H-1A is a solid state relay containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

It is suitable for analog signal control because of its low offset and high linearity.

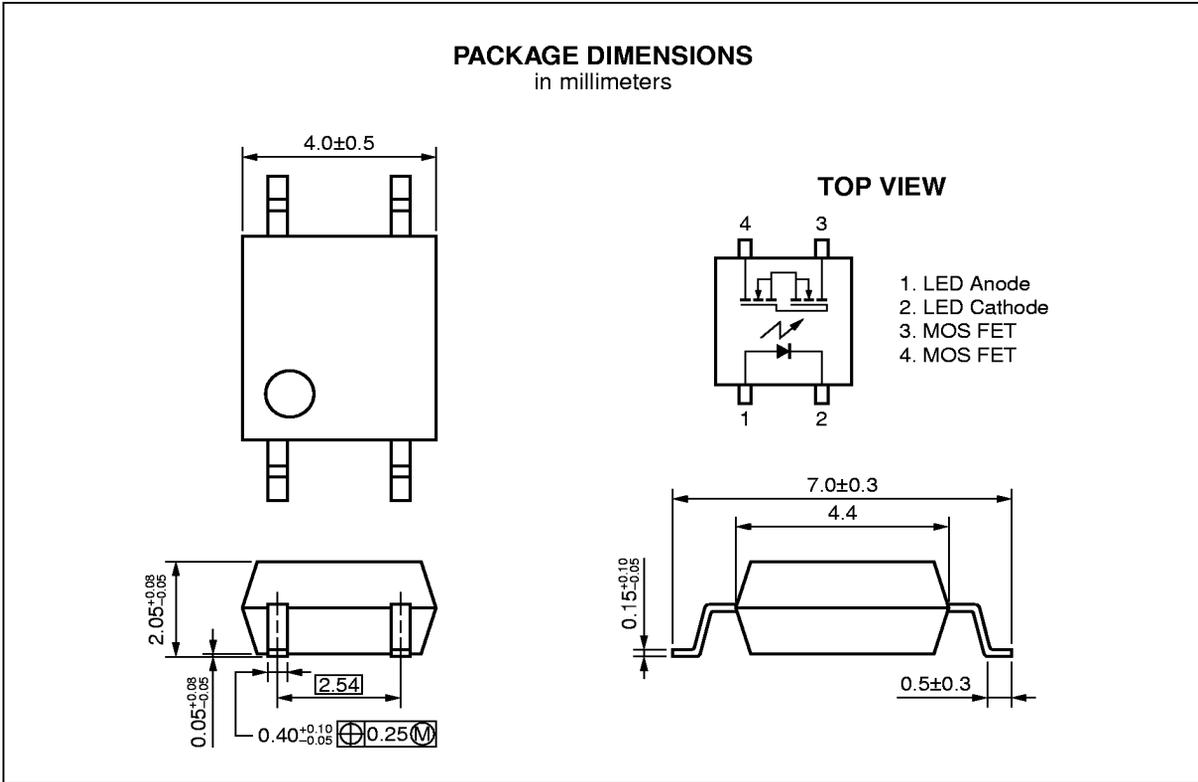
FEATURES

- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin package (4-pin SOP, Height = 2.1 mm)
- 1 channel type (1 a output)
- Low LED operating current ($I_F = 2$ mA)
- Designed for AC/DC switching line changer
- Low offset voltage
- Ordering number of taping product: PS7241H-1A-E3, E4, F3, F4

APPLICATIONS

- Laptop PC, PDA
- Modem card
- Telephone, FAX
- Measurement equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

| Parameter | | Symbol | Ratings | Unit |
|---------------------------------|------------------------------------|------------------|-------------|---------|
| Diode | Forward Current (DC) | I _F | 50 | mA |
| | Reverse Voltage | V _R | 5.0 | V |
| | Power Dissipation | P _D | 50 | mW |
| | Peak Forward Current ^{*1} | I _{FP} | 1 | A |
| MOS FET | Break Down Voltage | V _L | 400 | V |
| | Continuous Load Current | I _L | 120 | mA |
| | Power Dissipation | P _D | 300 | mW |
| Isolation Voltage ^{*2} | | BV | 3 750 | Vr.m.s. |
| Total Power Dissipation | | P _T | 350 | mW |
| Operating Ambient Temperature | | T _A | -40 to +80 | °C |
| Storage Temperature | | T _{stg} | -40 to +100 | °C |

*1 PW = 100 μs, Duty Cycle = 1 %

*2 AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS (T_A = 25 °C)

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|-----------------------|----------------|------|------|------|------|
| LED Operating Current | I _F | 2 | 10 | 20 | mA |
| LED Off Voltage | V _F | 0 | | 0.5 | V |

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------|---------------------------|--------------------|--|-----------------|------|------|------|
| Diode | Forward Voltage | V _F | I _F = 10 mA | | 1.2 | 1.4 | V |
| | Reverse Current | I _R | V _R = 5 V | | | 5.0 | μA |
| MOS FET | Off-state Leakage Current | I _{Loff} | V _D = 400 V | | | 1.0 | μA |
| | Output Capacitance | C _{out} | V _D = 0 V, f = 1 MHz | | 54 | | pF |
| Coupled | LED On-state Current | I _{Fon} | I _L = 120 mA | | | 2.0 | mA |
| | On-state Resistance | R _{on1} | I _F = 10 mA, I _L = 10 mA | | 18 | 30 | Ω |
| | | R _{on2} | I _F = 10 mA, I _L = 120 mA | | 15 | 25 | |
| | Turn-on Time | t _{on} | I _F = 10 mA, V _O = 5 V, PW ≥ 10 ms | | | 3.0 | ms |
| | Turn-off Time | t _{off} | | | | 0.2 | |
| | Isolation Resistance | R _{i-o} | V _{i-o} = 1.0 kV _{Dc} | 10 ⁹ | | | Ω |
| Isolation Capacitance | C _{i-o} | V = 0 V, f = 1 MHz | | 0.5 | | pF | |